

M5M82C55AP-5

PRELIMINARY
 Notice: This is not a final specification. Some parametric limits are Subject to change.

CMOS PROGRAMMABLE PERIPHERAL INTERFACE

MITSUBISHI (MICMPTR/MIPRC)

DESCRIPTION

This is a family of general-purpose programmable input/output devices designed for use with the 8/16-bit parallel CPU as input/output ports.

This device is fabricated using silicon-gate CMOS technology for a single supply voltage. This LSI is a simple input and output interface for TTL circuits, having 24 input/output pins which correspond to three 8-bit input/output ports.

FEATURES

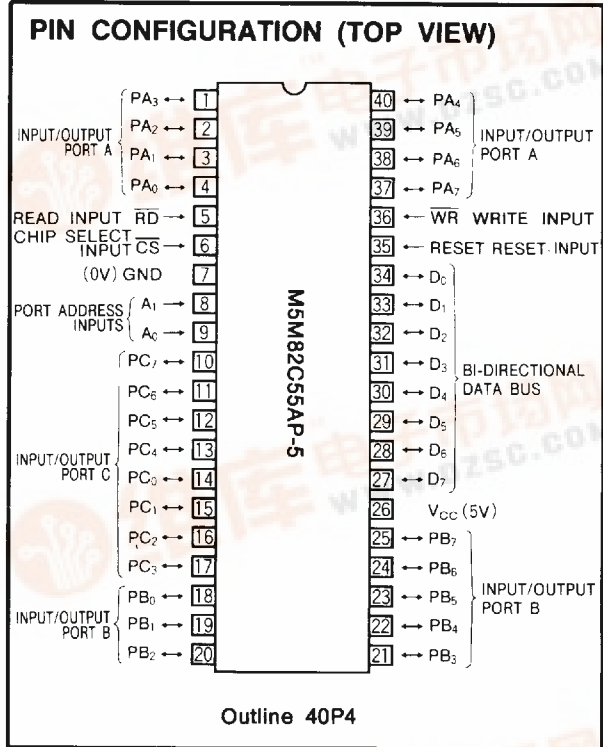
- 24 programmable I/O pins
- Single 5 V supply voltage
- TTL-compatible $I_{OL}=2.5\text{mA}$ (max.)
- Direct bit set/reset capability
- Improved DC driving capability
- Improved timing characteristics
- Fully compatible with MELPS85, MELPS86, MELPS88 microprocessor series

APPLICATION

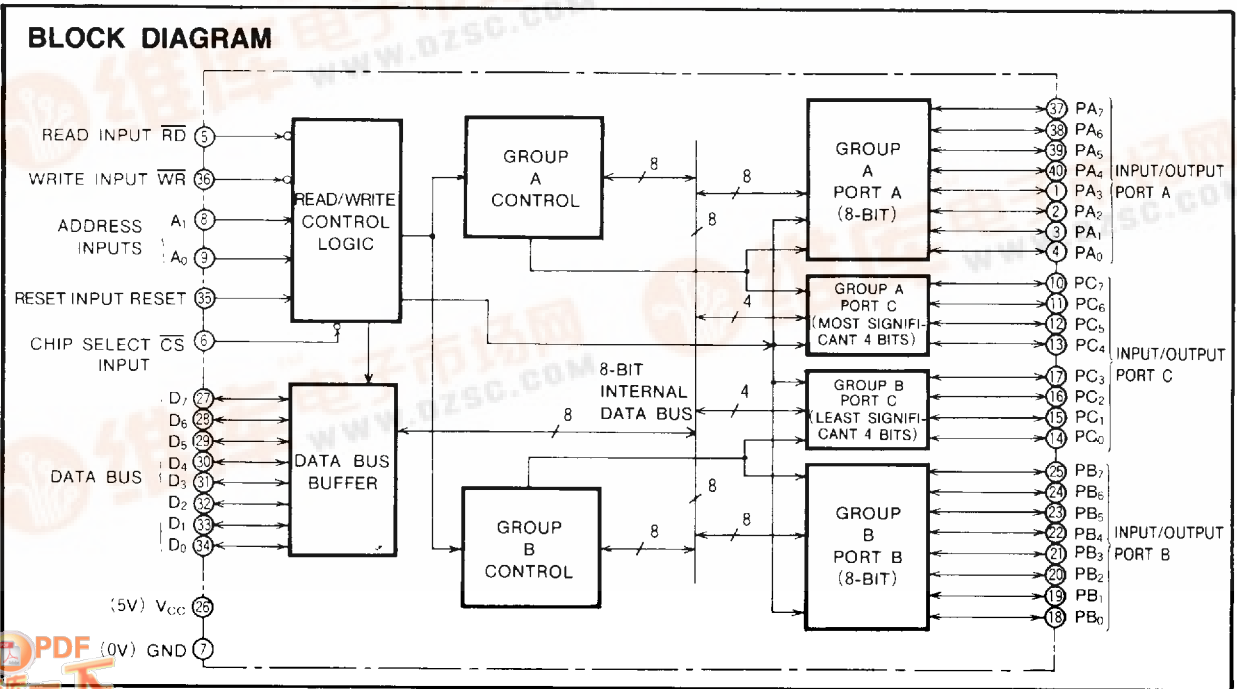
Input/output ports for MELPS85, MELPS86, MELPS88 microprocessor

FUNCTION

These PPIs have 24 input/output pins which may be individually programmed in two 12-bit groups A and B with mode control commands from a CPU. They are used in three major modes of operation, mode 0, mode 1 and mode 2. Operating in mode 0, each group of 12 pins may be programmed in sets of 4 to be inputs or outputs. In mode 1, the 24 I/O terminals may be programmed in two 12-bit groups, group A and group B. Each group contains one 8-bit data



port, which may be programmed to serve as input or output, and one 4-bit control port used for handshaking and interrupt control signals. Mode 2 is used with group A only, as one 8-bit bidirectional bus port and one 5-bit control port. Bit set/reset is controlled by CPU. A high-level reset input (RESET) clears all internal registers, and all ports are set to the input mode (high-impedance state).



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ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Conditions	Limits	Unit
V_{CC}	Supply voltage		-0.3~7	V
V_i	Input voltage	With respect to GND	-0.3~ $V_{CC}+0.3$	V
V_o	Output voltage		-0.3~ $V_{CC}+0.3$	V
T_{opr}	Operating free-air temperature range		-20~75	°C
T_{stg}	Storage temperature range		-65~150	°C

RECOMMENDED OPERATING CONDITIONS ($T_a = -20 \sim 75^\circ\text{C}$, unless otherwise noted)

Symbol	Parameter	Limits			Unit
		Min	Nom	Max	
V_{CC}	Supply voltage	4.5	5	5.5	V
GND	Supply voltage		0		V

ELECTRICAL CHARACTERISTICS ($T_a = -20 \sim 75^\circ\text{C}$, $V_{CC} = 5V \pm 10\%$, $GND = 0V$, unless otherwise noted)

Symbol	Parameter	Test conditions	Limits			Unit
			Min	Typ	Max	
V_{IH}	High-level input voltage		2.0		V_{CC}	V
V_{IL}	Low-level input voltage		0		0.8	V
V_{OH}	Output high voltage	$I_{OH} = -400\mu\text{A}$	2.4			V
V_{OL}	Output low voltage	$I_{OL} = 2.5\text{mA}$			0.45	V
I_{OH}	High-level output current (Note 2)	$GND = 0V$, $V_{OH} = 1.5V$, $R_{EXT} = 750\Omega$	-1		-4	mA
I_{CC}	Supply current from V_{CC}	$GND = 0V$, All input mode, $RESET = 0V$, Other pins = V_{CC} .			10	μA
I_{IH}	High-level input voltage	$GND = 0V$, $V_i = V_{CC}$			± 10	μA
I_{IL}	Low-level input voltage	$GND = 0V$, $V_i = 0V$			± 10	μA
I_{OZ}	Off-state output current	$GND = 0V$, $V_i = 0 \sim V_{CC}$			± 10	μA
C_i	Input capacitance	$V_{iL} = GND$, $f = 1\text{MHz}$, 25mVrms , $T_a = 25^\circ\text{C}$			10	pF
$C_{i/O}$	Input/output terminal capacitance	$V_{i/OL} = GND$, $f = 1\text{MHz}$, 25mVrms , $T_a = 25^\circ\text{C}$			20	pF

Note 1: Current flowing into an IC is positive, out is negative.
 2: It is valid for any 24input/output pins of PA, PB and PC.

TIMING REQUIREMENTS ($T_a = -20 \sim 75^\circ\text{C}$, $V_{CC} = 5V \pm 10\%$, $GND = 0V$, unless otherwise noted)

Symbol	Parameter	Alternative symbol	Test conditions	Limits			Unit
				Min	Typ	Max	
$t_{W(R)}$	Read pulse width	t_{RR}		200			ns
$t_{SU(PE-R)}$	Peripheral setup time before read	t_{iR}		0			ns
$t_{h(R-PE)}$	Peripheral hold time after read	t_{hR}		0			ns
$t_{SU(A-R)}$	Address setup time before read	t_{AR}		0			ns
$t_{h(R-A)}$	Address hold time after read	t_{RA}		0			ns
$t_{W(W)}$	Write pulse width	t_{WW}		200			ns
$t_{SU(DQ-W)}$	Data setup time before write	t_{DW}		100			ns
$t_{h(W-DQ)}$	Data hold time after write	t_{WD}		0			ns
$t_{SU(A-W)}$	Address setup time before write	t_{AW}		0			ns
$t_{h(W-A)}$	Address hold time after write	t_{WA}		0			ns
$t_{W(ACK)}$	Acknowledge pulse width	t_{AK}		300			ns
$t_{W(STB)}$	Strobe pulse width	t_{ST}		350			ns
$t_{SU(PE-STB)}$	Peripheral setup time before strobe	t_{PS}		0			ns
$t_{h(STB-PE)}$	Peripheral hold time after strobe	t_{PH}		150			ns
$t_{C(RW)}$	Read/write cycle time	t_{RV}		850			ns

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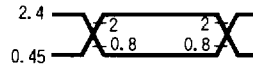
SWITCHING CHARACTERISTICS ($T_a = -20 \sim 75^\circ\text{C}$, $V_{cc} = 5V \pm 10\%$, unless otherwise noted)

Symbol	Parameter	Alternative symbol	Test conditions	Limits			Unit
				Min	Typ	Max	
$t_{PZX}(R-DO)$	Propagation time from read to data output	t_{RD}	$C_L = 150\text{pF}$			170	ns
$t_{PXZ}(R-DO)$	Propagation time from read to data floating (Note 3)	t_{DF}		10		100	ns
$t_{PHL}(W-PE)$ $t_{PLH}(W-PE)$	Propagation time from write to output	t_{WB}				350	ns
$t_{PLH}(STB-IBF)$	Propagation time from strobe to IBF flag	t_{SIB}				300	ns
$t_{PLH}(STB-INTR)$	Propagation time from strobe to interrupt	t_{SIT}				300	ns
$t_{PHL}(R-INTR)$	Propagation time from read to interrupt	t_{RIT}				400	ns
$t_{PHL}(R-IBF)$	Propagation time from read to IBF flag	t_{RIB}				300	ns
$t_{PHL}(W-INTR)$	Propagation time from write to interrupt	t_{WIT}				450	ns
$t_{PHL}(W-OBF)$	Propagation time from write to OBF flag	t_{WOB}				650	ns
$t_{PLH}(ACK-OBF)$	Propagation time from acknowledge to OBF flag	t_{AOB}				350	ns
$t_{PLH}(ACK-INTR)$	Propagation time from acknowledge to interrupt	t_{AIT}				350	ns
$t_{PZX}(ACK-PE)$	Propagation time from acknowledge to data output	t_{AD}				300	ns
$t_{PXZ}(ACK-PE)$	Propagation time from acknowledge to data floating (Note 3)	t_{KD}			20	250	ns

Note 3: Test conditions are not applied.

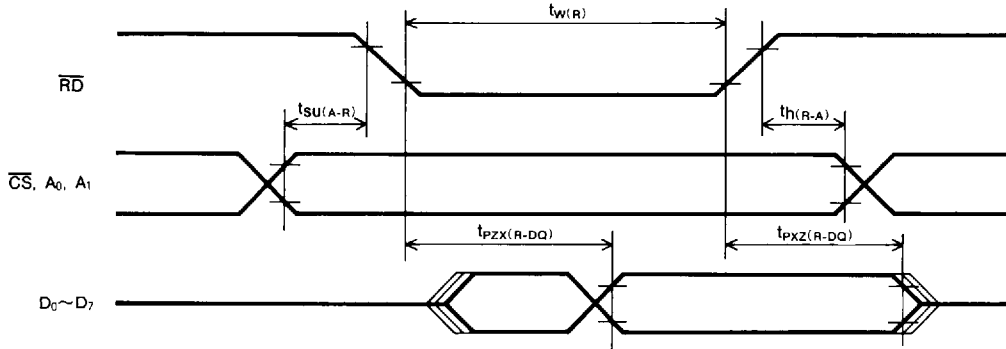
4: A.C Testing waveform

Input pulse level 0.45~2.4V
 Input pulse rise time 10ns
 Input pulse fall time 10ns
 Reference level input $V_{IH}=2V, V_{IL}=0.8V$
 Output $V_{OH}=2V, V_{OL}=0.8V$

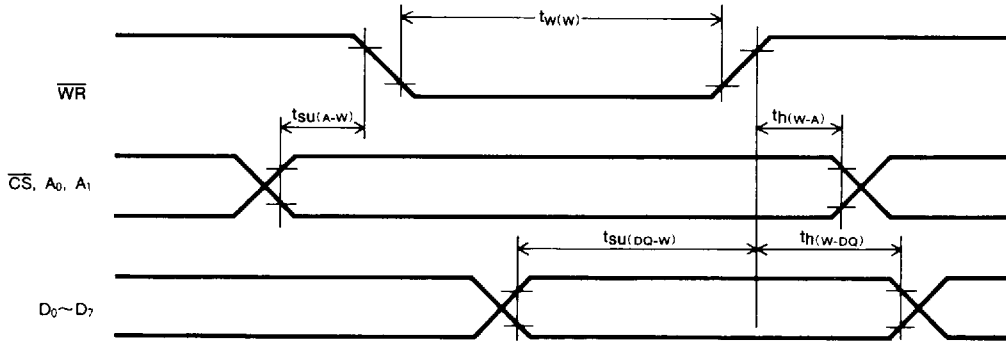


TIMING DIAGRAM

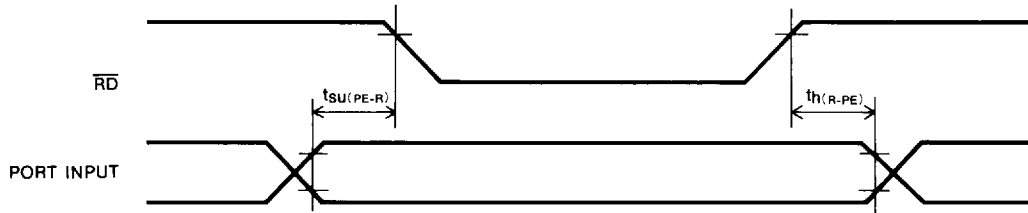
Data bus read operation



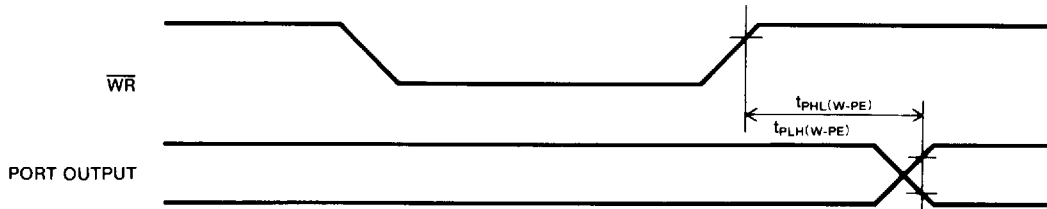
Data bus write operation



Mode 0 Port input



Mode 0, 1 Port output

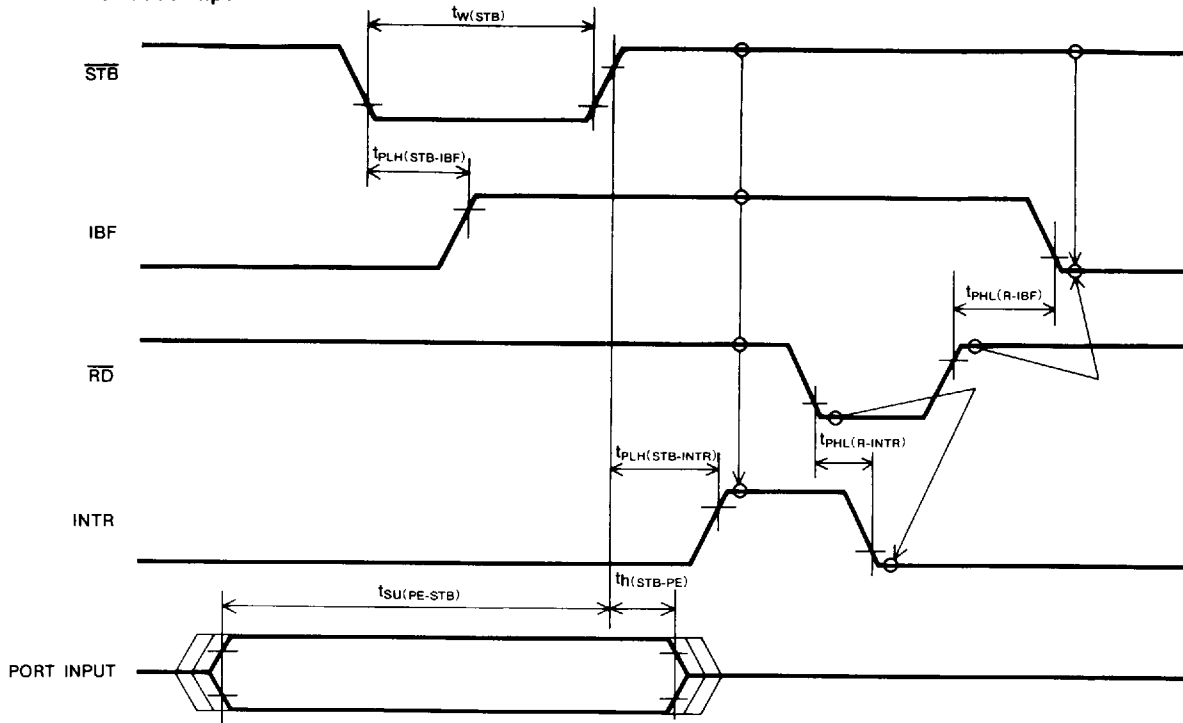


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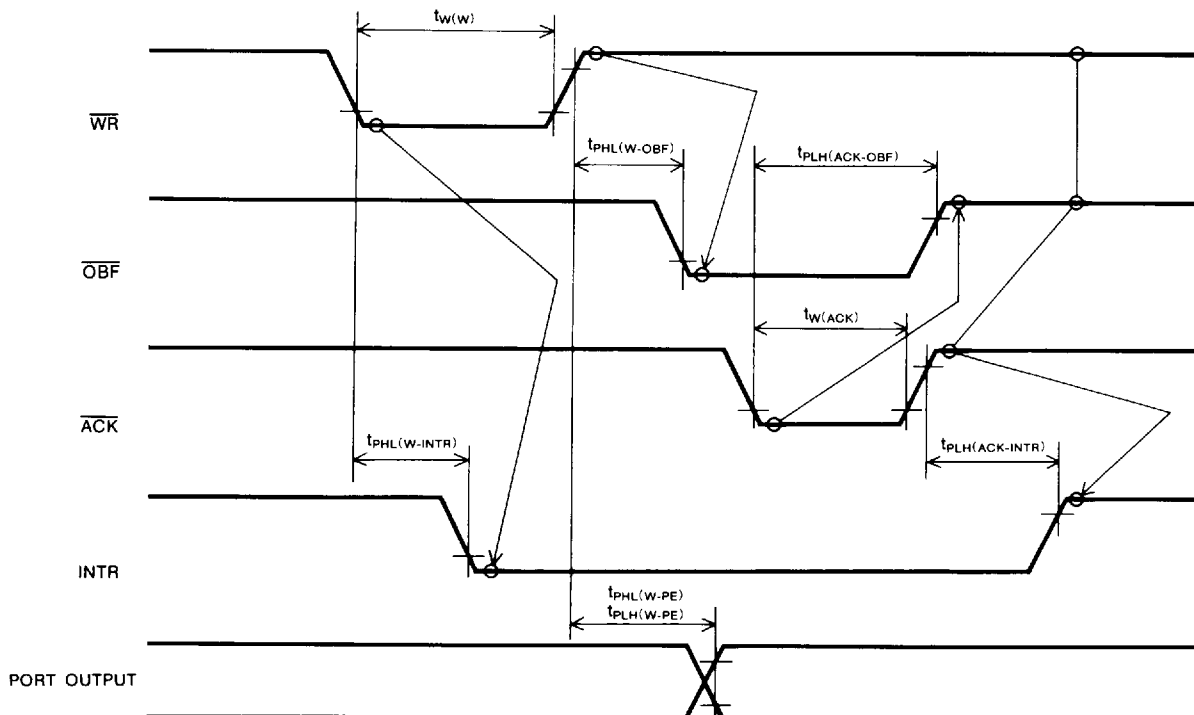
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Mode 1 Strobed input

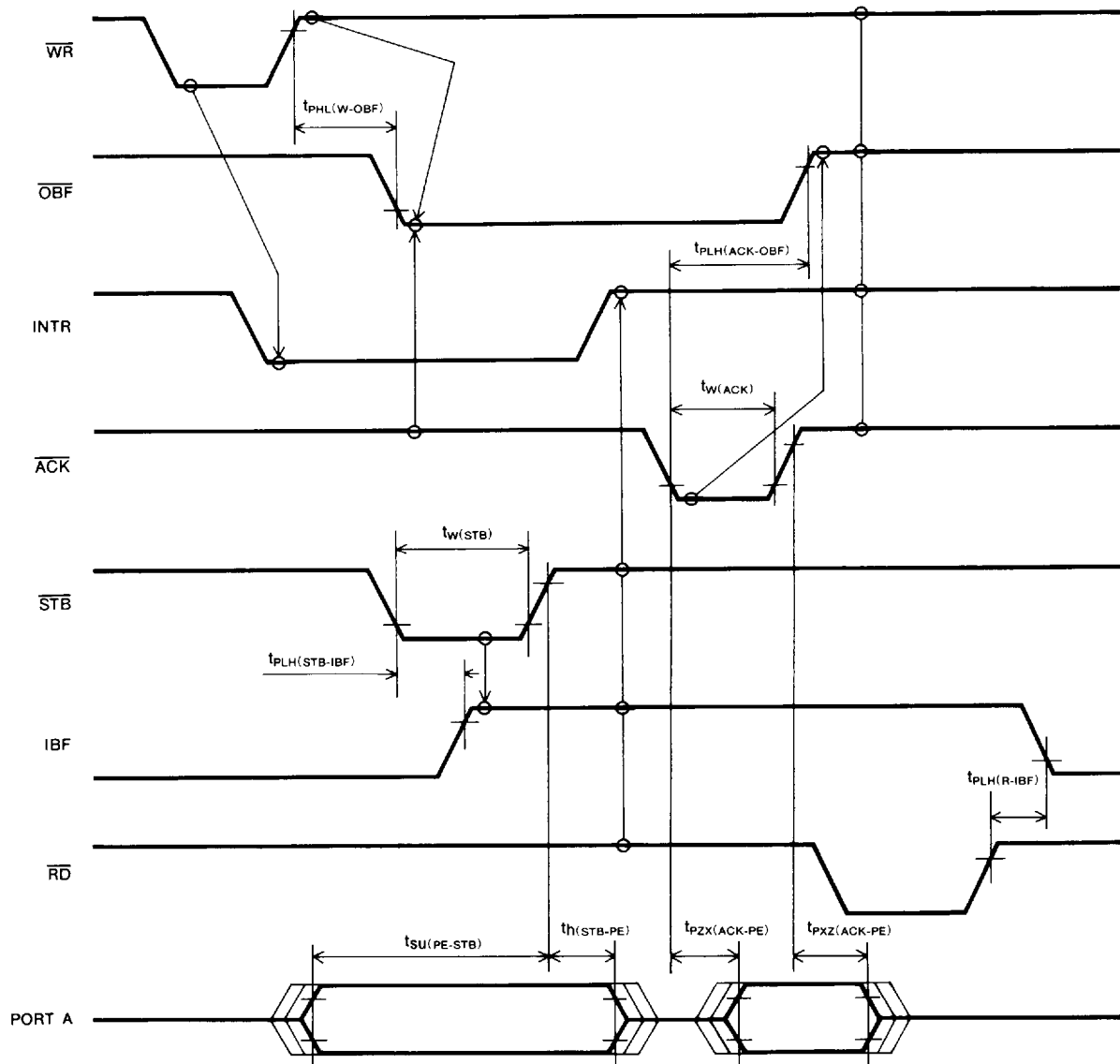


Mode 1 Strobed output



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Mode 2 Bidirectional



Note 5: $INTR = IBF \cdot MASK \cdot STB \cdot RD + OBF \cdot MASK \cdot ACK \cdot WR$